NTSX2102

Dual supply translating transceiver; open-drain; auto direction sensing

Rev. 2.3 — 6 October 2022

Product data sheet

1 General description

The NTSX2102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ($V_{CC(A)}$ and $V_{CC(B)}$). Both supplies can be supplied at any voltage between 1.65 V and 5.5 V. This flexibility makes the device suitable for translating between any of the voltage nodes (1.8 V, 2.5 V, 3.3 V, and 5.0 V). Pins An and OE are referenced to $V_{CC(A)}$ and pins Bn are referenced to $V_{CC(B)}$. A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2 Features and benefits

- Wide supply voltage range:
 - $V_{CC(A)}$: 1.65 V to 5.5 V and $V_{CC(B)}$: 1.65 V to 5.5 V
- Maximum data rates:
 - 50 Mbit/s
- I_{OFF} circuitry provides partial power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
 - HBM JS-001 Class 2 exceeds 2000 V
 - CDM JESD22-C101E exceeds 2000 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- · Multiple package options
- Specified from -40 °C to +85 °C

3 Applications

- I²C/SMBus
- UART
- GPIO



Dual supply translating transceiver; open-drain; auto direction sensing

4 Ordering information

Table 1. Ordering information

Type number	Topside	Package						
	marking	Name	Description	Version				
NTSX2102GU8	sX	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.4 × 1.2 × 0.5 mm	SOT1309-1				
NTSX2102GD	sX2	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm	SOT996-2				
NTSX2102TL	tX2	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm	SOT1052-2				

4.1 Ordering options

Table 2. Ordering options

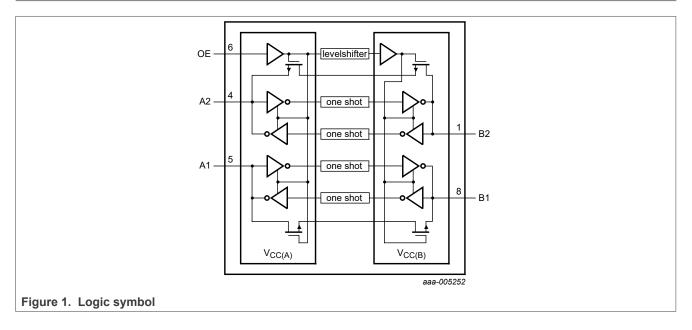
Type number	Orderable part number	Package	Y41	Minimum order quantity	Temperature
NTSX2102GU8	NTSX2102GU8H	XQFN8	Reel 7" Q3 NDP	4000	–40 °C to +85 °C
NTSX2102GD ^[2]	NTSX2102GDH	XSON8	Reel 7" Q3 NDP	3000	–40 °C to +85 °C
NTSX2102TL	NTSX2102TLH	XSON8	Reel 7" Q3 NDP	4000	–40 °C to +85 °C

^[1] Standard packing quantities and other packaging data are available at www.nxp.com/packages/.

The TL package has a center pad vs no center pad for the GD package. The TL package pad is not electrically connected to the silicon and is not required to connect to the PCB so it can drop onto the GD package PCB layout. If the existing GD package has a trace underneath the risk is low since the TL package center pad is not connected to the silicon. If there are multiple traces there could be EMI and cross talk. In both cases the customer needs to evaluate risk.

Note: The length and width are reversed between the "GD" and "TL" package drawings but the shorter edge contains the pins and is 2.0 mm in both cases.

5 Functional diagram



NTSX2102

All information provided in this document is subject to legal disclaimers.

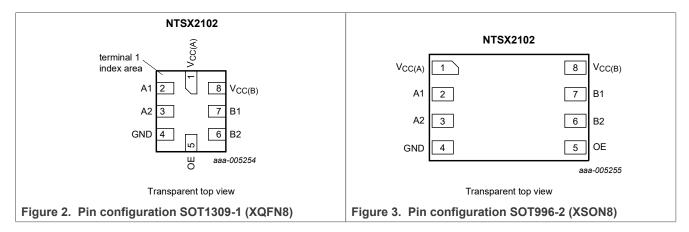
© 2022 NXP B.V. All rights reserved.

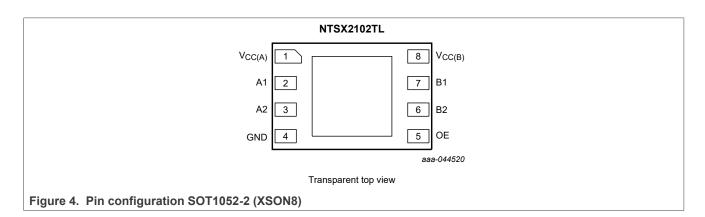
^[2] Discontinuation Notice 202111012DN - drop in replacement is NTSX0102TLH.

Dual supply translating transceiver; open-drain; auto direction sensing

6 Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
B2, B1	6, 7	data input or output (referenced to V _{CC(B)})
GND	4	ground (0 V)
V _{CC(A)}	1	supply voltage A
A2, A1	3, 2	data input or output (referenced to V _{CC(A)})
OE	5	output enable input (active HIGH; referenced to V _{CC(A)})
V _{CC(B)}	8	supply voltage B

Dual supply translating transceiver; open-drain; auto direction sensing

7 Functional description

Table 4. Function table^[1]

Supply voltage		Input	Input/output	
V _{CC(A)} V _{CC(B)}		OE	An	Bn
1.65 V to 5.5 V	1.65 V to 5.5 V	L	Z	Z
1.65 V to 5.5 V	1.65 V to 5.5 V	Н	input or output	output or input
GND ^[2]	GND ^[2]	Х	Z	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(A)}	supply voltage A			-0.5	+6.5	V
V _{CC(B)}	supply voltage B			-0.5	+6.5	V
VI	input voltage	A port and OE input	[1] [2]	-0.5	+6.5	V
		B port	[1] [2]	-0.5	+6.5	V
Vo	output voltage	Active mode	[1] [2]			
		A or B port		-0.5	V _{CCO} + 0.5	V
		Power-down or 3-state mode	[1]			
		A or B port		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		-50	_	mA
I _{OK}	output clamping current	V _O < 0 V		-50	_	mA
Io	output current	V _O = 0 V to V _{CCO}	[2]	_	±50	mA
I _{CC}	supply current	I _{CC(A)} or I _{CC(B)}		_	100	mA
I _{GND}	ground current			-100	_	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +85 °C		_	250	mW

^[1] If the input and output current ratings are observed, the minimum input and minimum output voltage ratings may be exceeded.

9 Recommended operating conditions

Table 6. Recommended operating conditions^[1]

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		1.65	5.5	V
V _{CC(B)}	supply voltage B		1.65	5.5	V

NTSX2102

All information provided in this document is subject to legal disclaimers.

© 2022 NXP B.V. All rights reserved.

^[2] When either $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into power-down mode.

^[2] V_{CCO} is the supply voltage associated with the output.

Dual supply translating transceiver; open-drain; auto direction sensing

Table 6. Recommended operating conditions^[1]...continued

Symbol	Parameter	Conditions	Min	Max	Unit
T _{amb}	ambient temperature		-40	+85	°C
Δt/ΔV	input transition rise and fall rate	A, B or OE port			
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V	_	10	ns/V

^[1] Hold the A and B sides of an unused I/O pair in the same state, both at V_{CCI} or both at GND.

10 Static characteristics

Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Cı	input capacitance	OE input; $V_{CC(A)} = V_{CC(B)} = 0 \text{ V}$	_	2.2	_	pF
C _{I/O}	input/output capacitance	A or B port; $V_{CC(A)} = 5.0 \text{ V}$; $V_{CC(B)} = 5.0 \text{ V}$	_	10	_	pF

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	o +85 °C	Unit
			Min	Max	
V _{IH}	HIGH-level input	A or B port			
	voltage	V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V	V _{CCI} - 0.4	_	V
		OE input			
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V	0.65V _{CC(A)}	_	V
V _{IL}	LOW-level input	A or B port			
	voltage	V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V	_	0.4	V
		OE input			
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V	_	0.35V _{CC(A)}	V
V _{OL}	LOW-level output	A or B port; $I_O = 6 \text{ mA}$			
	voltage	$V_1 \le 0.15 \text{ V}; V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	_	0.4	V
I _I	input leakage current	OE input; $V_I = 0 \text{ V to } V_{CC(A)}$; $V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}$; $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	_	±1	μΑ
l _{OZ}	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$; $V_{CC(A)} = 0 \text{ V to } 5.5 \text{ V}$; $V_{CC(B)} = 0 \text{ V to } 5.5 \text{ V}$	_	±2	μΑ
I _{OFF}	power-off leakage current	A port; V_I or V_O = 0 V to 5.5 V; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 0 V to 5.5 V	_	±2	μΑ
		B port; V_I or $V_O = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 0$ V to 5.5 V	_	±2	μA

Dual supply translating transceiver; open-drain; auto direction sensing

Table 8. Static characteristics...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	+85 °C	Unit
		-	Min	Max	
I _{CC}	supply current	$V_{I} = 0 \text{ V or } V_{CCI}; I_{O} = 0 \text{ A}$ [1]			
		I _{CC(A)}			
		$V_{CC(A)}$ = 1.65 V to 5.5 V; $V_{CC(B)}$ = 1.65 V to 5.5 V; OE = LOW or HIGH	_	5	μΑ
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 0 V	_	2	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 1.65 V to 5.5 V	_	-2	μA
		I _{CC(B)}			
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 1.65 V to 5.5 V; OE = LOW	_	5	μΑ
		V _{CC(A)} = 1.65 V to 5.5 V; V _{CC(B)} = 0 V	_	-2	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 1.65 V to 5.5 V	_	2	μA

^[1] V_{CCI} is the supply voltage associated with the input.

11 Dynamic characteristics

Table 9. Typical dynamic characteristics for temperature 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7; for waveforms see Figure 5 and Figure 6.

Symbol	Parameter	Conditions	V _{cco} ^[1]				
			1.8 V	2.5 V	3.3 V	5.0 V	1
t _{TLH}	LOW to HIGH output transition time	A or B port	7	5	4	3	ns
t _{THL}	HIGH to LOW output transition time	A or B port	4	6	8	11	ns
C _{PD}	power dissipation capacitance	OE = $V_{CC(A)}$; $V_{CC(A)} = V_{CC(B)}$; [3] $f_I = 400 \text{ kHz}$; $V_I = V_{CCI}$	_	_	_	13.5	pF

^[1] V_{CCO} is the supply voltage associated with the output.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

^[2] V_{CCO} is the supply voltage associated with the output.

^[2] V_{CCI} is the supply voltage associated with the input.

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

Dual supply translating transceiver; open-drain; auto direction sensing

Table 10. Dynamic characteristics for temperature range -40 °C to +85 °C^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>; for wave forms see <u>Figure 5</u> and <u>Figure 6</u>.

Symbol	Parameter	Conditions	$V_{\text{CC}(B)}$								Unit
			1.8 V ±	0.15 V	2.5 V ±	± 0.2 V	3.3 V ±	0.3 V	5.0 V ±	0.5 V	
			Тур	Max	Тур	Max	Тур	Max	Тур	Max	
V _{CC(A)} =	1.8 V ± 0.15 V	,									
t _{PHL}	HIGH to LOW propagation delay	A to B	3	7	3	6	3	5	5	7	ns
t _{PLH}	LOW to HIGH propagation delay	A to B	5	12	5	8	4	8	4	7	ns
t _{PHL}	HIGH to LOW propagation delay	B to A	3	7	3	6	3	5	5	7	ns
t _{PLH}	LOW to HIGH propagation delay	B to A	5	12	1	3	1	2	1	2	ns
t _{PZL}	OFF-state to LOW	OE to A	9	16	9	18	10	14	10	15	ns
	propagation delay	OE to B	9	16	6	12	6	12	6	14	ns
t _{PLZ}	LOW to OFF-state	OE to A	100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B	100	120	100	120	100	120	100	120	ns
t _{sk(o)}	output skew time	between channels [2]	_	1	_	1	_	1	_	1	ns
f _{data}	data rate		_	18	_	18	_	18	_	18	Mbit/s
V _{CC(A)} =	2.5 V ± 0.2 V						•				
t _{PHL}	HIGH to LOW propagation delay	A to B	3	6	2	5	2	5	2	5	ns
t _{PLH}	LOW to HIGH propagation delay	A to B	1	3	2	4	2.5	7	2.5	5	ns
t _{PHL}	HIGH to LOW propagation delay	B to A	3	6	2	5	2	5	2	5	ns
t _{PLH}	LOW to HIGH propagation delay	B to A	5	8	2	4	1.5	3	1	3	ns
t _{PZL}	OFF-state to LOW	OE to A	6	12	5	10	8	10	5	8	ns
	propagation delay	OE to B	9	18	5	10	4.5	9	4	8	ns
t _{PLZ}	LOW to OFF-state	OE to A	100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B	100	120	100	120	100	120	100	120	ns
t _{sk(o)}	output skew time	between channels [2]	_	1	_	1	_	1	_	1	ns
f _{data}	data rate		_	18	_	32	_	32	_	32	Mbit/s
V _{CC(A)} =	3.3 V ± 0.3 V		1		,				1		
t _{PHL}	HIGH to LOW propagation delay	A to B	3	5	2	5	2	4	2	4	ns
t _{PLH}	LOW to HIGH propagation delay	A to B	1	2	1.5	3	1.5	3	2	4	ns

Dual supply translating transceiver; open-drain; auto direction sensing

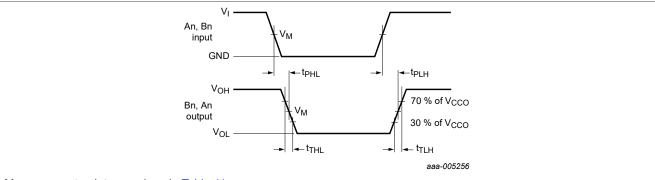
Table 10. Dynamic characteristics for temperature range -40 °C to +85 °C^[1]...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7; for wave forms see Figure 5 and Figure 6.

Symbol	Parameter	Conditions	V _{CC(B)}								Unit
			1.8 V ±	0.15 V	2.5 V ±	0.2 V	3.3 V ±	0.3 V	5.0 V ±	0.5 V	
			Тур	Max	Тур	Max	Тур	Max	Тур	Max	
t _{PHL}	HIGH to LOW propagation delay	B to A	3	5	2	5	2	4	2	4	ns
t _{PLH}	LOW to HIGH propagation delay	B to A	4	8	2.5	7	1.5	3	1	3	ns
t _{PZL}	OFF-state to LOW	OE to A	6	12	4.5	9	6	9	4	7	ns
	propagation delay	OE to B	10	14	5	10	6	9	4	8	ns
t _{PLZ}	LOW to OFF-state	OE to A	100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B	100	120	100	120	100	120	100	120	ns
t _{sk(o)}	output skew time	between channels [2]	_	1	_	1	_	1	_	1	ns
f _{data}	data rate		_	18	_	32	_	40	_	40	Mbit/s
V _{CC(A)} =	5.0 V ± 0.5 V										
t _{PHL}	HIGH to LOW propagation delay	A to B	5	7	2	5	2	4	2	4	ns
t _{PLH}	LOW to HIGH propagation delay	A to B	1	2	1	3	1	3	1	3	ns
t _{PHL}	HIGH to LOW propagation delay	B to A	5	7	2	5	2	4	2	4	ns
t _{PLH}	LOW to HIGH propagation delay	B to A	4	7	2.5	5	2	4	1	3	ns
t _{PZL}	OFF-state to LOW	OE to A	6	14	4	8	4	8	3	5	ns
	propagation delay	OE to B	10	15	5	8	4	7	4	5	ns
t _{PLZ}	LOW to OFF-state	OE to A	100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B	100	120	100	120	100	120	100	120	ns
t _{sk(o)}	output skew time	between channels [2]	_	1	_	1	_	1	_	1	ns
f _{data}	data rate		_	18	_	32	_	40	_	52	Mbit/

All typical values are measured at nominal V_{CC} and T_{amb} = 25 °C. Skew between any two outputs of the same package switching in the same direction.

Dual supply translating transceiver; open-drain; auto direction sensing

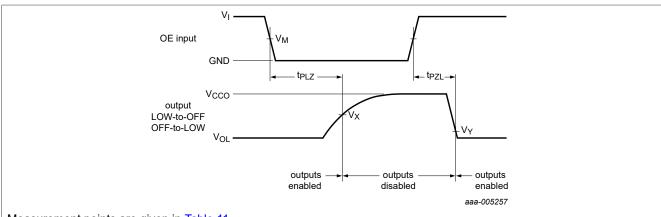
12 Waveforms



Measurement points are given in Table 11.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 5. The data input (An, Bn) to data output (Bn, An) propagation delay times



Measurement points are given in Table 11.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

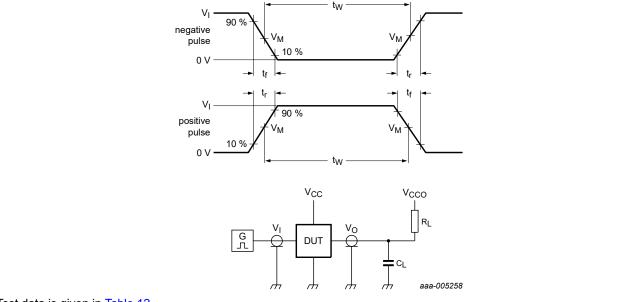
Figure 6. Enable and disable times

Table 11. Measurement points^{[1][2]}

Supply voltage	Input	Output		
V _{CCO}	V _M	V _M	V _X	V _Y
1.65 V to 5.5 V	0.5V _{CCI}	0.5V _{CCO}	0.5V _{CCO}	0.1V _{CCO}

- [1] V_{CCI} is the supply voltage associated with the input.
- [2] V_{CCO} is the supply voltage associated with the output.

Dual supply translating transceiver; open-drain; auto direction sensing



Test data is given in Table 12.

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; $Z_0 = 50 \Omega$; $dV/dt \geq 1.0 V/ns$.

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

V_{CC0} = Supply voltage associated with the output.

Figure 7. Test circuit for measuring switching times

Table 12. Test data

Supply voltage		Input		Load	
V _{CC(A)}	V _{CC(B)}	V _I ^[1]	t _r /t _f	C _L	R _L
1.65 V to 1.95 V	1.65 V to 1.95 V	V _{CCI}	≤ 2.0 ns	50 pF	2.2 kΩ
2.3 V to 2.7 V	2.3 V to 2.7 V	V _{CCI}	≤ 2.0 ns	50 pF	2.2 kΩ
3.0 V to 3.6 V	3.0 V to 3.6 V	V _{CCI}	≤ 2.5 ns	50 pF	2.2 kΩ
4.5 V to 5.5 V	4.5 V to 5.5 V	V _{CCI}	≤ 2.5 ns	50 pF	2.2 kΩ

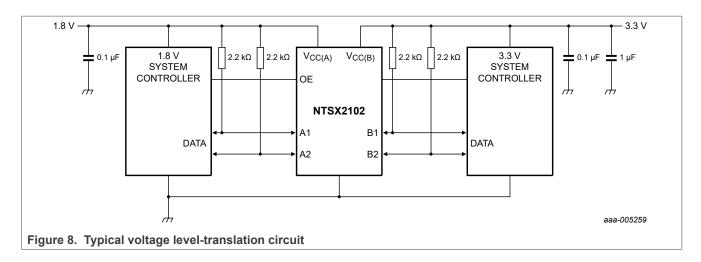
^[1] V_{CCI} is the supply voltage associated with the input.

13 Application information

13.1 Applications

The NTSX2102 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is targeted at I²C or 1-wire buses which use open-drain drivers.

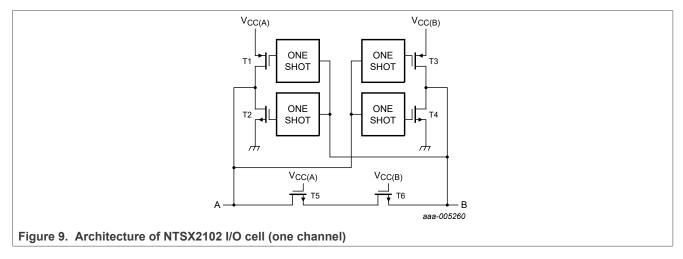
Dual supply translating transceiver; open-drain; auto direction sensing



13.2 Architecture

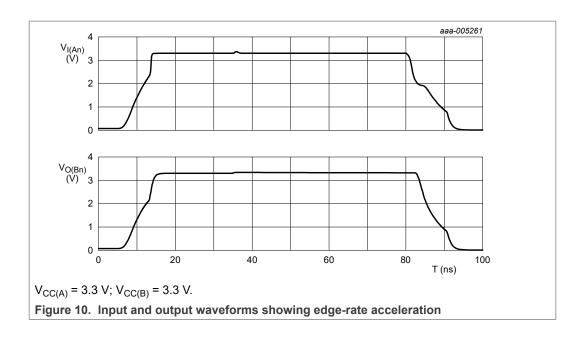
The architecture of the NTSX2102 is shown in Figure 9. The device does not require an extra input signal to control the direction of data flow from A to B or B to A. The NTSX2102 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

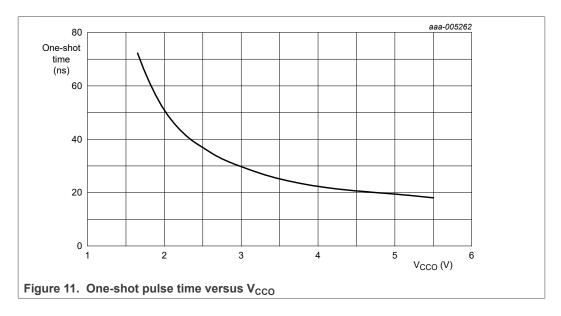
- 1. Two pass-gate transistors (N-channel) that tie the ports together.
- 2. An output edge-rate accelerator that detects and accelerates rising and falling edges on the I/O pins (see Figure 10).



During an input transition, a one-shot accelerates the output transition by switching on the PMOS transistors (T1, T3) for a LOW-to-HIGH transition. Alternatively, it switches on the NMOS transistors (T2, T4) for a HIGH-to-LOW transition. Once activated, the one-shot is de-activated after approximately 25 ns (see Figure 11). During the acceleration time, the driver output resistance is between approximately 10 Ω and 35 Ω . To avoid signal contention, the application must not exceed the maximum data rate or wait for the one-shot circuit to turn-off, before applying a signal in the opposite direction.

Dual supply translating transceiver; open-drain; auto direction sensing





13.3 Input driver requirements

As the NTSX2102 is a switch type translator, properties of the input driver directly affect the output signal. The external open-drain driver applied to an I/O, determines the static current sinking capability of the system. The maximum data rate, output transition times $(t_{THL},\,t_{TLH})$ and propagation delays $(t_{PHL},\,t_{PLH})$ are dependent upon the output impedance and edge-rate of the external driver.

13.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration and has been tuned to 600 pF. In cases with higher capacitive loading, there is a risk that the output does not reach the positive rail within the one-shot pulse

NTSX2102

All information provided in this document is subject to legal disclaimers.

© 2022 NXP B.V. All rights reserved.

Dual supply translating transceiver; open-drain; auto direction sensing

duration. To avoid excessive capacitive loading and to ensure correct triggering of the one-shot, use short trace lengths and low capacitance connectors on NTSX2102 PCB layouts. The length of the PCB trace should be such that the round-trip delay of any reflection is within the one-shot pulse duration. Such a length ensures low impedance termination and avoids output signal oscillations and one-shot retriggering.

13.5 Output enable (OE)

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state.

13.6 Power-up

When either of the supplies $V_{CC(n)}$ is at 0 V, outputs are in the high-impedance OFF-state. One of the advantages of NTSX translators is that either $V_{CC(A)}$ or $V_{CC(B)}$ may be powered up first. To reduce dissipation during power-up, ensure that output enable (OE) is defined. Connect it via a pulldown resistor to GND or, if the application allows, hardwired to $V_{CC(A)}$. If the OE pin is hardwired to $V_{CC(A)}$, either supply can be powered up or down first. If a pulldown is used, the following sequences are recommended.

For power-up:

- 1. Apply power to either supply pin
- 2. Apply power to other supply pin
- 3. Enable the device by driving OE HIGH

For power down:

- 1. Disable the device by driving OE LOW
- 2. Remove power from either supply pin
- 3. Remove power from other supply pin

13.7 Pull-up resistors on I/O lines

Each A port I/O requires a pull-up resistor to $V_{CC(A)}$, and each B port I/O requires a pull-up resistor to $V_{CC(B)}$. Choose the magnitude of the pull-up resistors to ensure that the output voltage levels meet the application requirement.

13.8 GD package vs TL package

Due to differences in package construction the TL package has a center pad vs no center pad for the GD package. The following section provides guidance in replacement vs new applications.

· No trace under GD package

 Replacement of GD package: The pad is not electrically connected to the silicon (no wire bond and epoxy is not conductive) and can be left floating. It is not required to be connected to the PCB. Simply place the TL package on the same PCB traces as the existing GD package.

Dual supply translating transceiver; open-drain; auto direction sensing

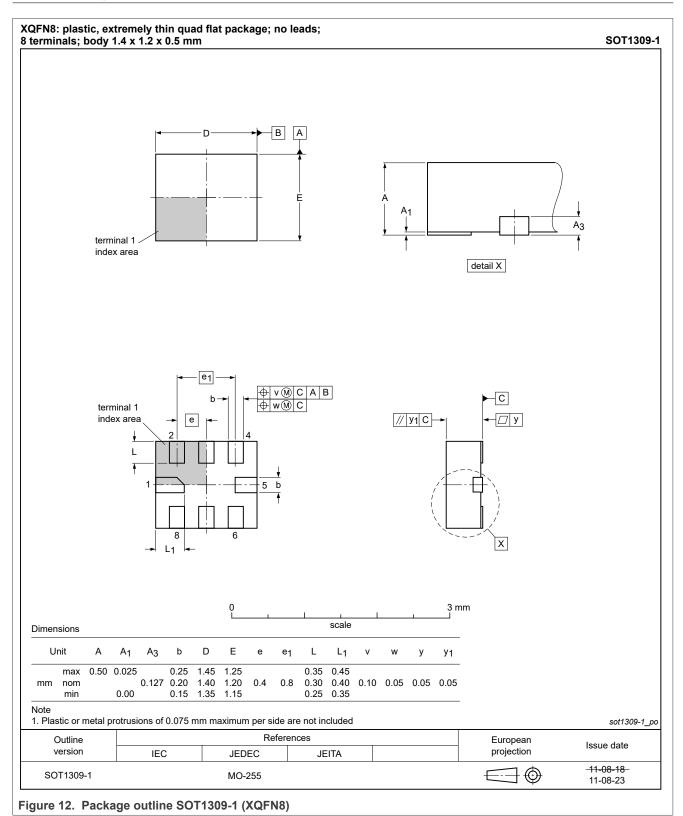
2. New use of the TL package: Place PCB trace for soldering of the center pad based on PCB layout recommendations for better mechanical connection and thermal conductivity. The PCB center pad can be connect to GND or left floating.

• Trace under the GD package

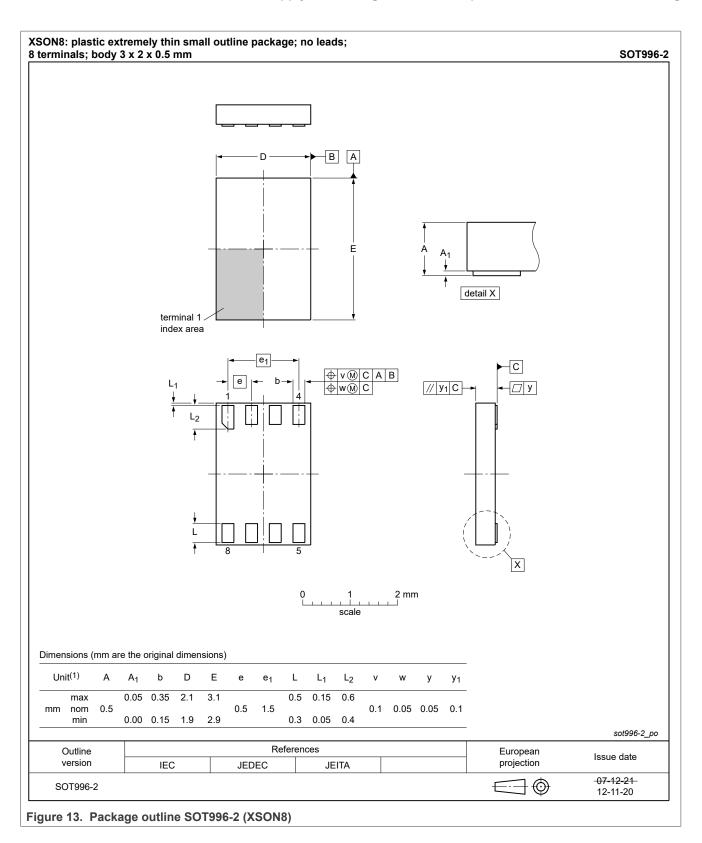
- Replacement of GD package: It is not best practice to have center pad over the trace but since the TL package center pad is not connected to the silicon the risk is low. If there are multiple traces there could be EMI and cross talk. In both cases the customer needs to evaluate risk.
- 2. New use of the TL package: Do not route traces under the package

Dual supply translating transceiver; open-drain; auto direction sensing

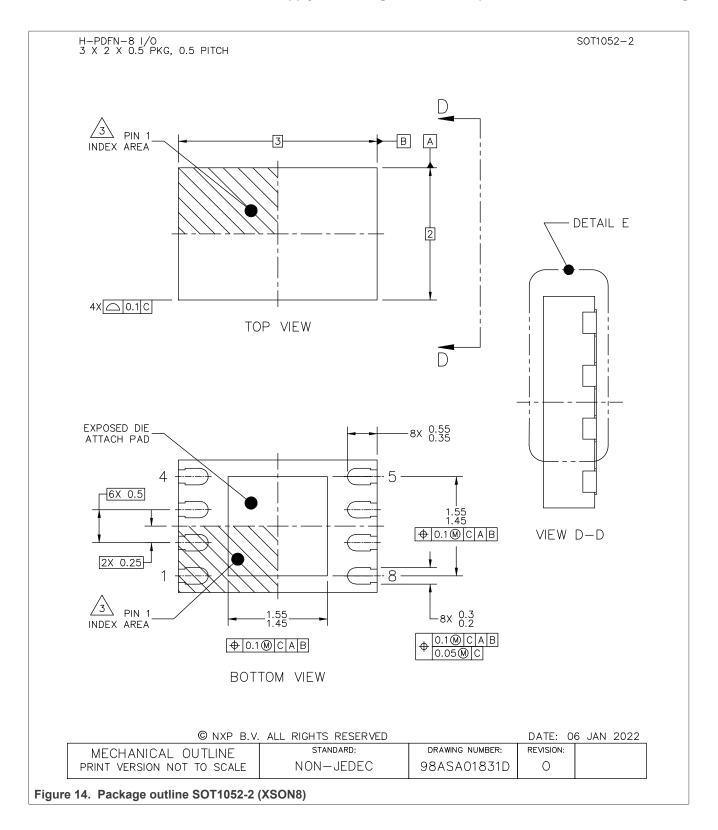
14 Package outline



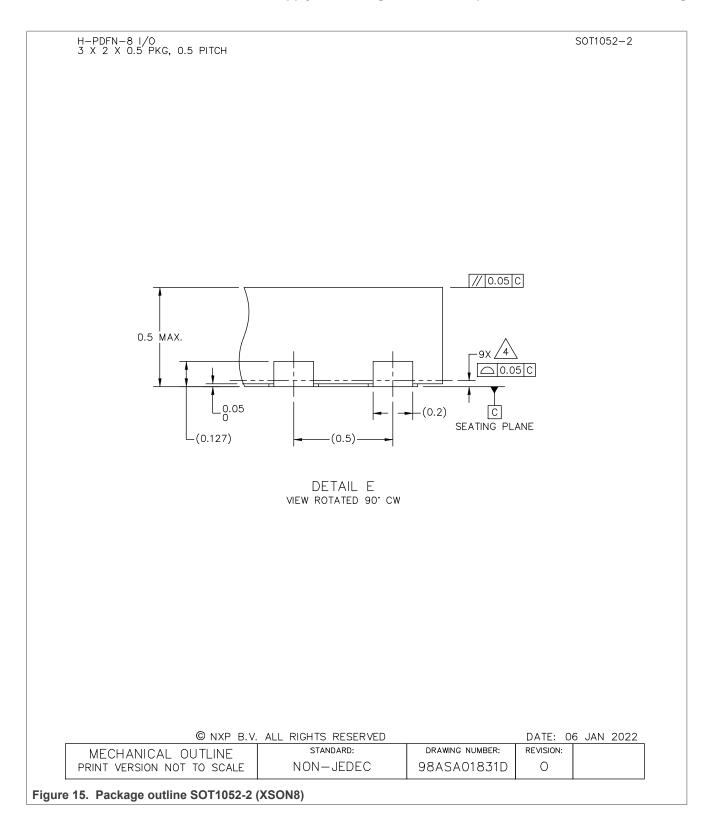
Dual supply translating transceiver; open-drain; auto direction sensing



Dual supply translating transceiver; open-drain; auto direction sensing



Dual supply translating transceiver; open-drain; auto direction sensing



NTSX2102

Dual supply translating transceiver; open-drain; auto direction sensing

15 Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

15.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

15.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- · Board specifications, including the board finish, solder masks and vias
- · Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- · Inspection and repair
- · Lead-free soldering versus SnPb soldering

15.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

15.4 Reflow soldering

Key characteristics in reflow soldering are:

© 2022 NXP B.V. All rights reserved

Dual supply translating transceiver; open-drain; auto direction sensing

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 16</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board
 is heated to the peak temperature) and cooling down. It is imperative that the peak
 temperature is high enough for the solder to make reliable solder joints (a solder
 paste characteristic). In addition, the peak temperature must be low enough that the
 packages and/or boards are not damaged. The peak temperature of the package
 depends on package thickness and volume and is classified in accordance with
 Table 13 and Table 14

Table 13. SnPb eutectic process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm³)		
	< 350	≥ 350	
< 2.5	235	220	
≥ 2.5	220	220	

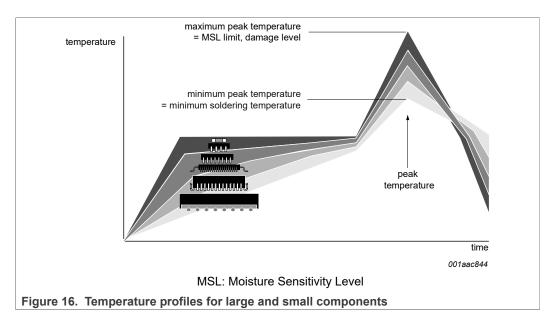
Table 14. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm³)		
	< 350	350 to 2000	> 2000
< 1.6	260	260	260
1.6 to 2.5	260	250	245
> 2.5	250	245	245

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see <u>Figure 16</u>.

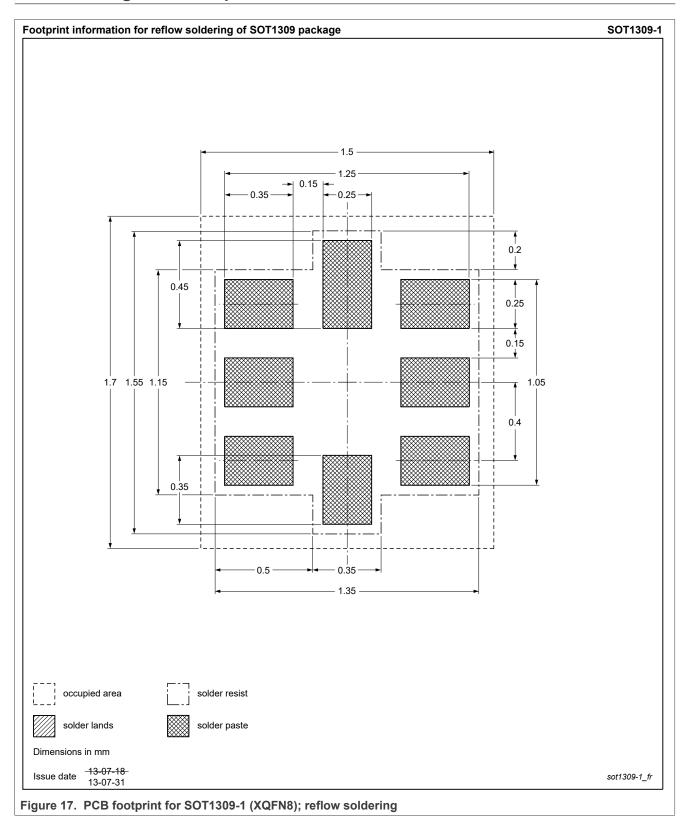
Dual supply translating transceiver; open-drain; auto direction sensing



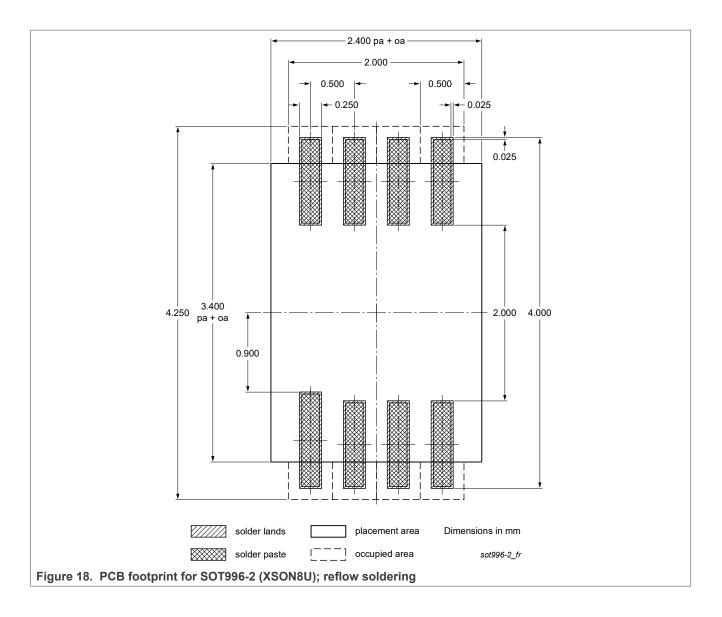
For further information on temperature profiles, refer to Application Note *AN10365* "Surface mount reflow soldering description".

Dual supply translating transceiver; open-drain; auto direction sensing

16 Soldering: PCB footprints



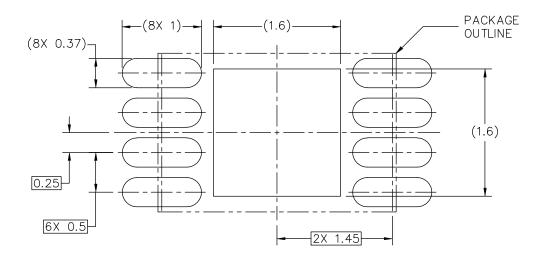
Dual supply translating transceiver; open-drain; auto direction sensing



Dual supply translating transceiver; open-drain; auto direction sensing



SOT1052-2



PCB DESIGN GUIDELINES RECOMMENDED SOLDER MASK OPENING PATTERN

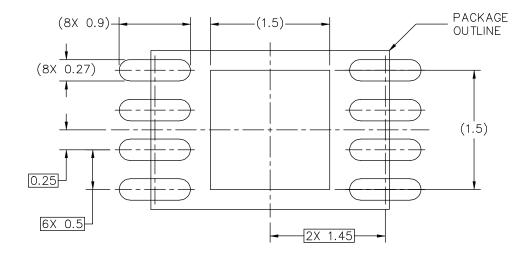
THIS SHEET SERVES ONLY AS A GUIDELINE TO HELP DEVELOP A USER SPECIFIC SOLUTION. DEVELOPMENT EFFORT WILL STILL BE REQUIRED BY END USERS TO OPTIMIZE PCB MOUNTING PROCESSES AND BOARD DESIGN IN ORDER TO MEET INDIVIDUAL/SPECIFIC REQUIREMENTS.

© NXP B.V. ALL RIGHTS RESERVED				6 JAN 2022
MECHANICAL OUTLINE	STANDARD:	DRAWING NUMBER:	REVISION:	
PRINT VERSION NOT TO SCALE	NON-JEDEC	98ASA01831D	0	

Figure 19. PCB footprint for SOT1052-2 (XSON8); recommended solder mask opening pattern

Dual supply translating transceiver; open-drain; auto direction sensing

H-PDFN-8 I/O 3 X 2 X 0.5 PKG, 0.5 PITCH SOT1052-2



PCB DESIGN GUIDELINES RECOMMENDED I/O PADS AND SOLDERABLE AREA

THIS SHEET SERVES ONLY AS A GUIDELINE TO HELP DEVELOP A USER SPECIFIC SOLUTION. DEVELOPMENT EFFORT WILL STILL BE REQUIRED BY END USERS TO OPTIMIZE PCB MOUNTING PROCESSES AND BOARD DESIGN IN ORDER TO MEET INDIVIDUAL/SPECIFIC REQUIREMENTS.

© NXP B.V. ALL RIGHTS RESERVED

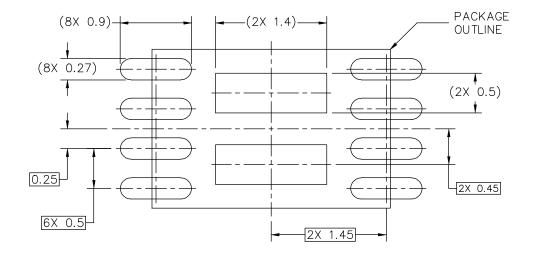
DATE: 06 JAN 2022

MECHANICAL OUTLINE	STANDARD:	DRAWING NUMBER:	REVISION:	
PRINT VERSION NOT TO SCALE	NON-JEDEC	98ASA01831D	0	

Figure 20. PCB footprint for SOT1052-2 (XSON8); recommended I/O pads and solderable area

Dual supply translating transceiver; open-drain; auto direction sensing

H-PDFN-8 I/O 3 X 2 X 0.5 PKG, 0.5 PITCH SOT1052-2



RECOMMENDED STENCIL THICKNESS 0.125

PCB DESIGN GUIDELINES - RECOMMENDED SOLDER PASTE STENCIL

THIS SHEET SERVES ONLY AS A GUIDELINE TO HELP DEVELOP A USER SPECIFIC SOLUTION. DEVELOPMENT EFFORT WILL STILL BE REQUIRED BY END USERS TO OPTIMIZE PCB MOUNTING PROCESSES AND BOARD DESIGN IN ORDER TO MEET INDIVIDUAL/SPECIFIC REQUIREMENTS.

© NXP B.V. ALL RIGHTS RESERVED

DATE: 06 JAN 2022

MECHANICAL OUTLINE	STANDARD:	DRAWING NUMBER:	REVISION:	
PRINT VERSION NOT TO SCALE	NON-JEDEC	98ASA01831D	0	

Figure 21. PCB footprint for SOT1052-2 (XSON8); recommended solder paste stencil

Dual supply translating transceiver; open-drain; auto direction sensing

H-PDFN-8 I/O 3 X 2 X 0.5 PKG, 0.5 PITCH SOT1052-2

NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

3. PIN 1 FEATURE SHAPE, SIZE AND LOCATION MAY VARY.
4. COPLANARITY APPLIES TO LEADS, DIE ATTACH FLAG.

5. MIN. METAL GAP FOR LEAD TO EXPOSED PAD SHALL BE 0.2 MM.

© NXP B.V. ALL RIGHTS RESERVED

DATE: 06 JAN 2022

MECHANICAL OUTLINE	STANDARD:	DRAWING NUMBER:	REVISION:	
PRINT VERSION NOT TO SCALE	NON-JEDEC	98ASA01831D	0	

Figure 22. PCB footprint for SOT1052-2 (XSON8); notes

Dual supply translating transceiver; open-drain; auto direction sensing

17 Abbreviations

Table 15. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
GPIO	General Purpose Input Output	
НВМ	Human Body Model	
I ² C	Inter-Integrated Circuit	
РСВ	Printed-circuit board	
PMOS	Positive Metal Oxide Semiconductor	
SMBus	System Management Bus	
UART	Universal Asynchronous Receiver Transmitter	
UTLP	Ultra Thin Leadless Package	

18 Revision history

Table 16. Revision history

Tuble 16. Revision mistory				
Release date	Data sheet status	Change notice	Supersedes	
20221006	Product data sheet	2022100081	NTSX2102 v.2.2	
Modifications: • Table 2: NTSX2102TL Minimum Order Quantity corrected to 4Ku per reel				
20220321	Product data sheet	_	NTSX2102 v.2.1	
20211112	Product data sheet	_	NTSX2102 v.2	
20130211	Product data sheet	_	NTSX2102 v.1.1	
20121121	Product data sheet	_	NTSX2102 v.1	
20121119	Product data sheet	_	_	
	Release date 20221006 Table 2: NTSX2 20220321 20211112 20130211 20121121	Release date Data sheet status 20221006 Product data sheet Table 2: NTSX2102TL Minimum Order Quantif 20220321 Product data sheet 20211112 Product data sheet 20130211 Product data sheet 20121121 Product data sheet	Release date Data sheet status Change notice 20221006 Product data sheet 202210008I • Table 2: NTSX2102TL Minimum Order Quantity corrected to 4Ku per 20220321 Product data sheet — 20211112 Product data sheet — 20130211 Product data sheet — 20121121 Product data sheet —	

Dual supply translating transceiver; open-drain; auto direction sensing

19 Legal information

19.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL https://www.nxp.com.

19.2 Definitions

Draft — A draft status on a document indicates that the content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included in a draft version of a document and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

19.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

NTSX2102

All information provided in this document is subject to legal disclaimers.

© 2022 NXP B.V. All rights reserved.

Dual supply translating transceiver; open-drain; auto direction sensing

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Suitability for use in non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document, including the legal information in that document, is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Security — Customer understands that all NXP products may be subject to unidentified vulnerabilities or may support established security standards or specifications with known limitations. Customer is responsible for the design and operation of its applications and products throughout their lifecycles to reduce the effect of these vulnerabilities on customer's applications and products. Customer's responsibility also extends to other open and/or proprietary technologies supported by NXP products for use in customer's applications. NXP accepts no liability for any vulnerability. Customer should regularly check security updates from NXP and follow up appropriately. Customer shall select products with security features that best meet rules, regulations, and standards of the intended application and make the ultimate design decisions regarding its products and is solely responsible for compliance with all legal, regulatory, and security related requirements concerning its products, regardless of any information or support that may be provided by NXP.

NXP has a Product Security Incident Response Team (PSIRT) (reachable at PSIRT@nxp.com) that manages the investigation, reporting, and solution release to security vulnerabilities of NXP products.

19.4 Trademarks

Notice: All referenced brands, product names, service names, and trademarks are the property of their respective owners.

NXP — wordmark and logo are trademarks of NXP B.V.

Dual supply translating transceiver; open-drain; auto direction sensing

Tables

Tab. 1. Tab. 2. Tab. 3. Tab. 4. Tab. 5. Tab. 6. Tab. 7. Tab. 8. Tab. 9.	Ordering information 2 Ordering options 2 Pin description 3 Function table 4 Limiting values 4 Recommended operating conditions 4 Typical static characteristics 5 Static characteristics 5 Typical dynamic characteristics for temperature 25 °C 6	Tab. 10. Tab. 11. Tab. 12. Tab. 13. Tab. 14. Tab. 15. Tab. 16.	Dynamic characteristics for temperature range -40 °C to +85 °C	9 20 20
Figur	res			
Fig. 1.	Logic symbol2	Fig. 15.	Package outline SOT1052-2 (XSON8)	18
Fig. 2. Fig. 3.	Pin configuration SOT1309-1 (XQFN8)	Fig. 16.	Temperature profiles for large and small components	21
Fig. 3.	Pin configuration SOT1052-2 (XSON8)3	Fig. 17.	PCB footprint for SOT1309-1 (XQFN8);	∠ 1
Fig. 5.	The data input (An, Bn) to data output (Bn,	Ü	reflow soldering	22
	An) propagation delay times9	Fig. 18.	PCB footprint for SOT996-2 (XSON8U);	
Fig. 6.	Enable and disable times9	F: 40	reflow soldering	23
Fig. 7.	Test circuit for measuring switching times 10	Fig. 19.	PCB footprint for SOT1052-2 (XSON8);	24
Fig. 8. Fig. 9.	Typical voltage level-translation circuit 11 Architecture of NTSX2102 I/O cell (one	Fig. 20.	recommended solder mask opening pattern PCB footprint for SOT1052-2 (XSON8);	24
1 ig. 5.	channel)11	1 ig. 20.	recommended I/O pads and solderable	
Fig. 10.	Input and output waveforms showing edge-		area	25
5	rate acceleration12	Fig. 21.	PCB footprint for SOT1052-2 (XSON8);	
Fig. 11.	One-shot pulse time versus VCCO12	J	recommended solder paste stencil	26
Fig. 12.	Package outline SOT1309-1 (XQFN8)15	Fig. 22.	PCB footprint for SOT1052-2 (XSON8);	
Fig. 13.	Package outline SOT996-2 (XSON8)16	-	notes	27
Fig. 14.	Package outline SOT1052-2 (XSON8)17			

Dual supply translating transceiver; open-drain; auto direction sensing

Contents

1	General description	
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
4.1	Ordering options	2
5	Functional diagram	
6	Pinning information	3
6.1	Pinning	
6.2	Pin description	
7	Functional description	
8	Limiting values	
9	Recommended operating conditions	
10	Static characteristics	
11	Dynamic characteristics	
12	Waveforms	
13	Application information	
13.1	Applications	
13.2	Architecture	
13.3	Input driver requirements	
13.4	Output load considerations	
13.5	Output enable (OE)	13
13.6	Power-up	
13.7	Pull-up resistors on I/O lines	
13.8	GD package vs TL package	13
14	Package outline	15
15	Soldering of SMD packages	
15.1	Introduction to soldering	
15.2	Wave and reflow soldering	
15.3	Wave soldering	
15.4	Reflow soldering	
16	Soldering: PCB footprints	
17	Abbreviations	28
18	Revision history	
19	Legal information	29

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.